

165MHz, Rail-to-Rail Input and Output, 0.95nV/ $\sqrt{\text{Hz}}$ Low Noise, Op Amp Family

FEATURES

- Low Noise Voltage: 0.95nV/ $\sqrt{\text{Hz}}$ (100kHz)
- Gain Bandwidth Product:

LT6200/LT6201	165MHz	$A_V = 1$
LT6200-5	800MHz	$A_V \geq 5$
LT6200-10	1.6GHz	$A_V \geq 10$
- Low Distortion: -80dB at 1MHz, $R_L = 100\Omega$
- Dual LT6201 in Tiny DFN Package
- Input Common Mode Range Includes Both Rails
- Output Swings Rail-to-Rail
- Low Offset Voltage: 1mV Max
- Wide Supply Range: 2.5V to 12.6V
- Output Current: 60mA Min
- Operating Temperature Range -40°C to 85°C
- Power Shutdown, Thermal Shutdown
- SO-8 and Low Profile (1mm) ThinSOT™ Packages

APPLICATIONS

- Transimpedance Amplifiers
- Low Noise Signal Processing
- Active Filters
- Rail-to-Rail Buffer Amplifiers
- Driving A/D Converters

DESCRIPTION

The LT®6200/LT6201 are single and dual ultralow noise, rail-to-rail input and output unity gain stable op amps that feature 0.95nV/ $\sqrt{\text{Hz}}$ noise voltage. These amplifiers combine very low noise with a 165MHz gain bandwidth, 50V/ μs slew rate and are optimized for low voltage signal conditioning systems. A shutdown pin reduces supply current during standby conditions and thermal shutdown protects the part from overload conditions.

The LT6200-5/LT6200-10 are single amplifiers optimized for higher gain applications resulting in higher gain bandwidth and slew rate. The LT6200 family maintains its performance for supplies from 2.5V to 12.6V and are specified at 3V, 5V and $\pm 5\text{V}$.

For compact layouts the LT6200/LT6200-5/LT6200-10 are available in the 6-lead ThinSOT™ and the 8-pin SO package. The dual LT6201 is available in an 8-pin SO package with standard pinouts as well as a tiny, dual fine pitch leadless package (DFN). These amplifiers can be used as plug-in replacements for many high speed op amps to improve input/output range and noise performance.

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TYPICAL APPLICATION

Single Supply, 1.5nV/ $\sqrt{\text{Hz}}$, Photodiode Amplifier



6200 TA01

Distortion vs Frequency



6200 G35

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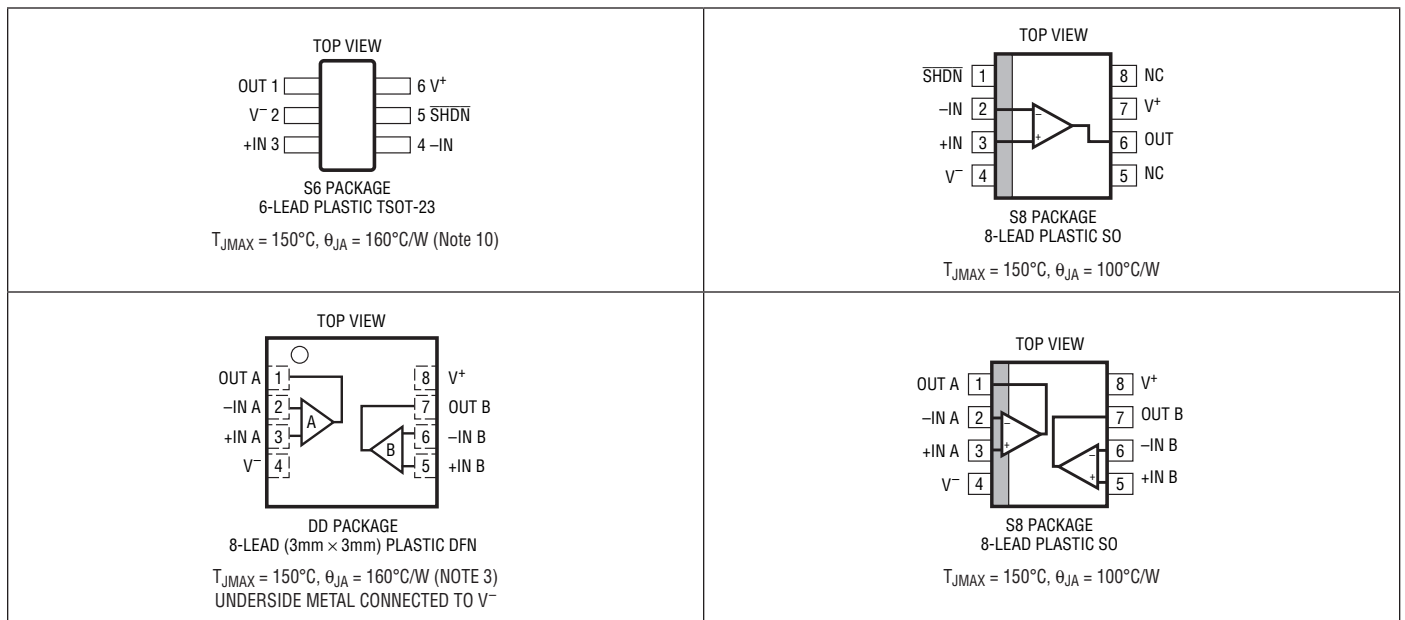
LT6200/LT6200-5 LT6200-10/LT6201

ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V^+ to V^-) 12.6V
 Total Supply Voltage (V^+ to V^-) (LT6201DD) 7V
 Input Current (Note 2)..... $\pm 40\text{mA}$
 Output Short-Circuit Duration (Note 3) Indefinite
 Pin Current While Exceeding Supplies
 (Note 12) $\pm 30\text{mA}$
 Operating Temperature Range (Note 4).... -40°C to 85°C

Specified Temperature Range (Note 5) -40°C to 85°C
 Junction Temperature 150°C
 Junction Temperature (DD Package)..... 125°C
 Storage Temperature Range..... -65°C to 150°C
 Storage Temperature Range
 (DD Package)..... -65°C to 125°C
 Lead Temperature (Soldering, 10 sec) 300°C

PIN CONFIGURATION



ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT6200CS6#PBF	LT6200CS6#TRPBF	LTJZ	6-Lead Plastic TSOT-23	0°C to 70°C
LT6200IS6#PBF	LT6200IS6#TRPBF	LTJZ	6-Lead Plastic TSOT-23	-40°C to 85°C
LT6200CS6-5#PBF	LT6200CS6-5#TRPBF	LTACB	6-Lead Plastic TSOT-23	0°C to 70°C
LT6200IS6-5#PBF	LT6200IS6-5#TRPBF	LTACB	6-Lead Plastic TSOT-23	-40°C to 85°C
LT6200CS6-10#PBF	LT6200CS6-10#TRPBF	LTACC	6-Lead Plastic TSOT-23	0°C to 70°C
LT6200IS6-10#PBF	LT6200IS6-10#TRPBF	LTACC	6-Lead Plastic TSOT-23	-40°C to 85°C
LT6200CS8#PBF	LT6200CS8#TRPBF	6200	8-Lead Plastic SO	0°C to 70°C
LT6200IS8#PBF	LT6200IS8#TRPBF	6200I	8-Lead Plastic SO	-40°C to 85°C
LT6200CS8-5#PBF	LT6200CS8-5#TRPBF	62005	8-Lead Plastic SO	0°C to 70°C
LT6200IS8-5#PBF	LT6200IS8-5#TRPBF	6200I5	8-Lead Plastic SO	-40°C to 85°C

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ORDER INFORMATION

LEAD FREE FINISH	TAPE AND REEL	PART MARKING*	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE
LT6200CS8-10#PBF	LT6200CS8-10#TRPBF	620010	8-Lead Plastic SO	0°C to 70°C
LT6200IS8-10#PBF	LT6200IS8-10#TRPBF	200110	8-Lead Plastic SO	-40°C to 85°C
LT6201CDD#PBF	LT6201CDD #TRPBF	LADG	8-Lead (3mm × 3mm) Plastic DFN	0°C to 70°C
LT6201CS8#PBF	LT6201CS8 #TRPBF	6201	8-Lead Plastic SO	0°C to 70°C
LT6201IS8 #PBF	LT6201IS8 #TRPBF	62011	8-Lead Plastic SO	-40°C to 85°C

Consult LTC Marketing for parts specified with wider operating temperature ranges. *The temperature grade is identified by a label on the shipping container. Consult LTC Marketing for information on non-standard lead based finish parts.

For more information on lead free part marking, go to: <http://www.linear.com/leadfree/>

For more information on tape and reel specifications, go to: <http://www.linear.com/tapeandreeel/>

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = 5\text{V}$, 0V ; $V_S = 3\text{V}$, 0V ; $V_{CM} = V_{OUT} = \text{half supply}$, $V_{SHDN} = \text{OPEN}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_S = 5\text{V}$, $V_{CM} = \text{Half Supply}$		0.1	1	mV
		$V_S = 3\text{V}$, $V_{CM} = \text{Half Supply}$		0.9	2.5	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	$V_{CM} = \text{Half Supply}$		0.2	1.1	mV
		$V_{CM} = V^- \text{ to } V^+$		0.5	2.2	mV
I_B	Input Bias Current	$V_{CM} = \text{Half Supply}$	-40	-10		μA
		$V_{CM} = V^+$		8	18	μA
		$V_{CM} = V^-$	-50	-23		μA
ΔI_B	I_B Shift	$V_{CM} = V^- \text{ to } V^+$		31	68	μA
	I_B Match (Channel-to-Channel) (Note 11)	$V_{CM} = V^- \text{ to } V^+$		0.3	5	μA
I_{OS}	Input Offset Current	$V_{CM} = \text{Half Supply}$		0.1	4	μA
		$V_{CM} = V^+$		0.02	4	μA
		$V_{CM} = V^-$		0.4	5	μA
	Input Noise Voltage	0.1Hz to 10Hz		600		nV _{p-p}
e_n	Input Noise Voltage Density	$f = 100\text{kHz}$, $V_S = 5\text{V}$		1.1		nV/ $\sqrt{\text{Hz}}$
		$f = 10\text{kHz}$, $V_S = 5\text{V}$		1.5	2.4	nV/ $\sqrt{\text{Hz}}$
i_n	Input Noise Current Density, Balanced Source Unbalanced Source	$f = 10\text{kHz}$, $V_S = 5\text{V}$		2.2		pA/ $\sqrt{\text{Hz}}$
		$f = 10\text{kHz}$, $V_S = 5\text{V}$		3.5		pA/ $\sqrt{\text{Hz}}$
	Input Resistance	Common Mode		0.57		M Ω
		Differential Mode		2.1		k Ω
C_{IN}	Input Capacitance	Common Mode		3.1		pF
		Differential Mode		4.2		pF
A_{VOL}	Large-Signal Gain	$V_S = 5\text{V}$, $V_O = 0.5\text{V to } 4.5\text{V}$, $R_L = 1\text{k to } V_S/2$	70	120		V/mV
		$V_S = 5\text{V}$, $V_O = 1\text{V to } 4\text{V}$, $R_L = 100\Omega \text{ to } V_S/2$	11	18		V/mV
		$V_S = 3\text{V}$, $V_O = 0.5\text{V to } 2.5\text{V}$, $R_L = 1\text{k to } V_S/2$	17	70		V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}$, $V_{CM} = V^- \text{ to } V^+$	65	90		dB
		$V_S = 5\text{V}$, $V_{CM} = 1.5\text{V to } 3.5\text{V}$	85	112		dB
		$V_S = 3\text{V}$, $V_{CM} = V^- \text{ to } V^+$	60	85		dB
	CMRR Match (Channel-to-Channel) (Note 11)	$V_S = 5\text{V}$, $V_{CM} = 1.5\text{V to } 3.5\text{V}$	80	105		dB
PSRR	Power Supply Rejection Ratio	$V_S = 2.5\text{V to } 10\text{V}$, LT6201DD $V_S = 2.5\text{V to } 7\text{V}$	60	68		dB
		$V_S = 2.5\text{V to } 10\text{V}$, LT6201DD $V_S = 2.5\text{V to } 7\text{V}$	65	100		dB
	Minimum Supply Voltage (Note 6)		2.5			V

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LT6200/LT6200-5 LT6200-10/LT6201

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{CM} = V_{OUT} = \text{half supply}$, $V_{SHDN} = \text{OPEN}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OL}	Output Voltage Swing LOW (Note 7)	No Load		9	50	mV
		$I_{SINK} = 5\text{mA}$		50	100	mV
		$V_S = 5\text{V}, I_{SINK} = 20\text{mA}$		150	290	mV
		$V_S = 3\text{V}, I_{SINK} = 20\text{mA}$		160	300	mV
V_{OH}	Output Voltage Swing HIGH (Note 7)	No Load		55	110	mV
		$I_{SOURCE} = 5\text{mA}$		95	190	mV
		$V_S = 5\text{V}, I_{SOURCE} = 20\text{mA}$		220	400	mV
		$V_S = 3\text{V}, I_{SOURCE} = 20\text{mA}$		240	450	mV
I_{SC}	Short-Circuit Current	$V_S = 5\text{V}$	± 60	± 90		mA
		$V_S = 3\text{V}$	± 50	± 80		mA
I_S	Supply Current per Amplifier	$V_S = 5\text{V}$		16.5	20	mA
		$V_S = 3\text{V}$		15	18	mA
	Disabled Supply Current per Amplifier	$V_{SHDN} = 0.3\text{V}$		1.3	1.8	mA
I_{SHDN}	SHDN Pin Current	$V_{SHDN} = 0.3\text{V}$		200	280	μA
V_L	V_{SHDN} Pin Input Voltage LOW				0.3	V
V_H	V_{SHDN} Pin Input Voltage HIGH		$V^+ - 0.5$			V
	Shutdown Output Leakage Current	$V_{SHDN} = 0.3\text{V}$		0.1	75	μA
t_{ON}	Turn-On Time	$V_{SHDN} = 0.3\text{V}$ to 4.5V , $R_L = 100\Omega$, $V_S = 5\text{V}$		180		ns
t_{OFF}	Turn-Off Time	$V_{SHDN} = 4.5\text{V}$ to 0.3V , $R_L = 100\Omega$, $V_S = 5\text{V}$		180		ns
GBW	Gain Bandwidth Product	Frequency = 1MHz , $V_S = 5\text{V}$				
		LT6200, LT6201		145		MHz
		LT6200-5		750		MHz
		LT6200-10		1450		MHz
SR	Slew Rate	$V_S = 5\text{V}$, $A_V = -1$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200, LT6201	31	44		$\text{V}/\mu\text{s}$
		$V_S = 5\text{V}$, $A_V = -10$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200-5		210		$\text{V}/\mu\text{s}$
		LT6200-10		340		$\text{V}/\mu\text{s}$
FPBW	Full Power Bandwidth (Note 9)	$V_S = 5\text{V}$, $V_{OUT} = 3V_{P-P}$ (LT6200)	3.28	4.66		MHz
t_S	Settling Time (LT6200, LT6201)	0.1%, $V_S = 5\text{V}$, $V_{STEP} = 2\text{V}$, $A_V = -1$, $R_L = 1\text{k}$		165		ns

The ● denotes the specifications which apply over $0^\circ\text{C} < T_A < 70^\circ\text{C}$ temperature range. $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{CM} = V_{OUT} = \text{half supply}$, $V_{SHDN} = \text{OPEN}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_S = 5\text{V}$, $V_{CM} = \text{Half Supply}$	●	0.2	1.2	mV
		$V_S = 3\text{V}$, $V_{CM} = \text{Half Supply}$	●	1	2.7	mV
		$V_S = 5\text{V}$, $V_{CM} = V^+$ to V^-	●	0.3	3	mV
		$V_S = 3\text{V}$, $V_{CM} = V^+$ to V^-	●	1.5	4	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	$V_{CM} = \text{Half Supply}$	●	0.2	1.8	mV
		$V_{CM} = V^-$ to V^+	●	0.4	2.8	mV
$V_{OS\ TC}$	Input Offset Voltage Drift (Note 8)	$V_{CM} = \text{Half Supply}$	●	2.5	8	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	$V_{CM} = \text{Half Supply}$	●	-40	-10	μA
		$V_{CM} = V^+$	●		8	μA
		$V_{CM} = V^-$	●	-50	-23	μA
	I_B Match (Channel-to-Channel) (Note 11)	$V_{CM} = V^-$ to V^+	●	0.5	6	μA
ΔI_B	I_B Shift	$V_{CM} = V^-$ to V^+	●	31	68	μA
I_{OS}	Input Offset Current	$V_{CM} = \text{Half Supply}$	●	0.1	4	μA
		$V_{CM} = V^+$	●	0.02	4	μA
		$V_{CM} = V^-$	●	0.4	5	μA

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ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over 0°C < T_A < 70°C temperature range. V_S = 5V, 0V; V_S = 3V, 0V; V_{CM} = V_{OUT} = half supply, V_{SHDN} = OPEN, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
A _{VOL}	Large-Signal Gain	V _S = 5V, V _O = 0.5V to 4.5V, R _L = 1k to V _S /2	●	46	80	V/mV	
		V _S = 5V, V _O = 1.5V to 3.5V, R _L = 100Ω to V _S /2	●	7.5	13	V/mV	
		V _S = 3V, V _O = 0.5V to 2.5V, R _L = 1k to V _S /2	●	13	22	V/mV	
CMRR	Common Mode Rejection Ratio	V _S = 5V, V _{CM} = V ⁻ to V ⁺	●	64	88	dB	
		V _S = 5V, V _{CM} = 1.5V to 3.5V	●	80	105	dB	
		V _S = 3V, V _{CM} = V ⁻ to V ⁺	●	60	83	dB	
	CMRR Match (Channel-to-Channel) (Note 11)	V _S = 5V, V _{CM} = 1.5V to 3.5V	●	80	105	dB	
PSRR	Power Supply Rejection Ratio	V _S = 3V to 10V, LT6201DD V _S = 3V to 7V	●	60	65	dB	
		PSRR Match (Channel-to-Channel) (Note 11)	V _S = 3V to 10V, LT6201DD V _S = 3V to 7V	●	60	100	dB
		Minimum Supply Voltage (Note 6)	●	3		V	
V _{OL}	Output Voltage Swing LOW (Note 7)	No Load	●		12	60	mV
		I _{SINK} = 5mA	●		55	110	mV
		V _S = 5V, I _{SINK} = 20mA	●		170	310	mV
		V _S = 3V, I _{SINK} = 20mA	●		170	310	mV
V _{OH}	Output Voltage Swing HIGH (Note 7)	No Load	●		65	120	mV
		I _{SOURCE} = 5mA	●		115	210	mV
		V _S = 5V, I _{SOURCE} = 20mA	●		260	440	mV
		V _S = 3V, I _{SOURCE} = 20mA	●		270	490	mV
I _{SC}	Short-Circuit Current	V _S = 5V	●	±60	±90	mA	
		V _S = 3V	●	±45	±75	mA	
I _S	Supply Current per Amplifier	V _S = 5V	●		20	23	mA
		V _S = 3V	●		19	22	mA
		V _{SHDN} = 0.3V	●		1.35	1.8	mA
I _{SHDN}	SHDN Pin Current	V _{SHDN} = 0.3V	●		215	295	μA
V _L	V _{SHDN} Pin Input Voltage LOW		●			0.3	V
V _H	V _{SHDN} Pin Input Voltage HIGH		●	V ⁺ -0.5			V
	Shutdown Output Leakage Current	V _{SHDN} = 0.3V	●		0.1	75	μA
t _{ON}	Turn-On Time	V _{SHDN} = 0.3V to 4.5V, R _L = 100Ω, V _S = 5V	●		180		ns
t _{OFF}	Turn-Off Time	V _{SHDN} = 4.5V to 0.3V, R _L = 100Ω, V _S = 5V	●		180		ns
SR	Slew Rate	V _S = 5V, A _V = -1, R _L = 1k, V _O = 4V LT6200, LT6201	●	29	42		V/μs
		V _S = 5V, A _V = -10, R _L = 1k, V _O = 4V LT6200-5	●		190		V/μs
		LT6200-10	●		310		V/μs
FPBW	Full Power Bandwidth (Note 9)	V _S = 5V, V _{OUT} = 3V _{P-P} (LT6200)	●	3.07	4.45		MHz

The ● denotes the specifications which apply over -40°C < T_A < 85°C temperature range. Excludes the LT6201 in the DD package (Note 3). V_S = 5V, 0V; V_S = 3V, 0V; V_{CM} = V_{OUT} = half supply, V_{SHDN} = OPEN, unless otherwise noted. (Note 5)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
V _{OS}	Input Offset Voltage	V _S = 5V, V _{CM} = Half Supply	●		0.2	1.5	mV
		V _S = 3V, V _{CM} = Half Supply	●		1	2.8	mV
		V _S = 5V, V _{CM} = V ⁺ to V ⁻	●		0.3	3.5	mV
		V _S = 3V, V _{CM} = V ⁺ to V ⁻	●		1.5	4.3	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	V _{CM} = Half Supply V _{CM} = V ⁻ to V ⁺	●		0.2	2	mV
			●		0.4	3	mV
V _{OS} TC	Input Offset Voltage Drift (Note 8)	V _{CM} = Half Supply	●		2.5	8	μV/°C
I _B	Input Bias Current	V _{CM} = Half Supply	●	-40	-10		μA
		V _{CM} = V ⁺	●		8	18	μA
		V _{CM} = V ⁻	●	-50	-23		μA

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LT6200/LT6200-5 LT6200-10/LT6201

ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ temperature range. Excludes the LT6201 in the DD package (Note 3). $V_S = 5\text{V}, 0\text{V}$; $V_S = 3\text{V}, 0\text{V}$; $V_{\text{CM}} = V_{\text{OUT}} = \text{half supply}$, $V_{\text{SHDN}} = \text{OPEN}$, unless otherwise noted. (Note 5)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
ΔI_B	I_B Shift	$V_{\text{CM}} = V^- \text{ to } V^+$	●	31	68	μA
	I_B Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = V^- \text{ to } V^+$	●	1	9	μA
I_{OS}	Input Offset Current	$V_{\text{CM}} = \text{Half Supply}$	●	0.1	4	μA
		$V_{\text{CM}} = V^+$	●	0.02	4	μA
		$V_{\text{CM}} = V^-$	●	0.4	5	μA
A_{VOL}	Large-Signal Gain	$V_S = 5\text{V}, V_O = 0.5\text{V to } 4.5\text{V}, R_L = 1\text{k to } V_S/2$	●	40	70	V/mV
		$V_S = 5\text{V}, V_O = 1.5\text{V to } 3.5\text{V}, R_L = 100\Omega \text{ to } V_S/2$	●	7.5	13	V/mV
		$V_S = 3\text{V}, V_O = 0.5\text{V to } 2.5\text{V}, R_L = 1\text{k to } V_S/2$	●	11	20	V/mV
CMRR	Common Mode Rejection Ratio	$V_S = 5\text{V}, V_{\text{CM}} = V^- \text{ to } V^+$	●	60	80	dB
		$V_S = 5\text{V}, V_{\text{CM}} = 1.5\text{V to } 3.5\text{V}$	●	80	100	dB
		$V_S = 3\text{V}, V_{\text{CM}} = V^- \text{ to } V^+$	●	60	80	dB
	CMRR Match (Channel-to-Channel) (Note 11)	$V_S = 5\text{V}, V_{\text{CM}} = 1.5\text{V to } 3.5\text{V}$	●	75	105	dB
PSRR	Power Supply Rejection Ratio	$V_S = 3\text{V to } 10\text{V}$	●	60	68	dB
		$V_S = 3\text{V to } 10\text{V}$	●	60	100	dB
		Minimum Supply Voltage (Note 6)	●	3		V
V_{OL}	Output Voltage Swing LOW (Note 7)	No Load	●	18	70	mV
		$I_{\text{SINK}} = 5\text{mA}$	●	60	120	mV
		$V_S = 5\text{V}, I_{\text{SINK}} = 20\text{mA}$	●	170	310	mV
		$V_S = 3\text{V}, I_{\text{SINK}} = 20\text{mA}$	●	175	315	mV
V_{OH}	Output Voltage Swing HIGH (Note 7)	No Load	●	65	120	mV
		$I_{\text{SOURCE}} = 5\text{mA}$	●	115	210	mV
		$V_S = 5\text{V}, I_{\text{SOURCE}} = 20\text{mA}$	●	270	450	mV
		$V_S = 3\text{V}, I_{\text{SOURCE}} = 20\text{mA}$	●	280	500	mV
I_{SC}	Short-Circuit Current	$V_S = 5\text{V}$	●	± 50	± 80	mA
		$V_S = 3\text{V}$	●	± 30	± 60	mA
I_S	Supply Current per Amplifier	$V_S = 5\text{V}$	●	22	25.3	mA
	Disabled Supply Current per Amplifier	$V_S = 3\text{V}$ $V_{\text{SHDN}} = 0.3\text{V}$	●	20 1.4	23 1.9	mA mA
I_{SHDN}	SHDN Pin Current	$V_{\text{SHDN}} = 0.3\text{V}$	●	220	300	μA
V_L	V_{SHDN} Pin Input Voltage LOW		●		0.3	V
V_H	V_{SHDN} Pin Input Voltage HIGH		●	$V^+ - 0.5$		V
	Shutdown Output Leakage Current	$V_{\text{SHDN}} = 0.3\text{V}$	●	0.1	75	μA
t_{ON}	Turn-On Time	$V_{\text{SHDN}} = 0.3\text{V to } 4.5\text{V}, R_L = 100\Omega, V_S = 5\text{V}$	●	180		ns
t_{OFF}	Turn-Off Time	$V_{\text{SHDN}} = 4.5\text{V to } 0.3\text{V}, R_L = 100\Omega, V_S = 5\text{V}$	●	180		ns
SR	Slew Rate	$V_S = 5\text{V}, A_V = -1, R_L = 1\text{k}, V_O = 4\text{V}$ LT6200, LT6201	●	23	33	V/ μs
		$V_S = 5\text{V}, A_V = -10, R_L = 1\text{k}, V_O = 4\text{V}$ LT6200-5 LT6200-10	●		160 260	V/ μs V/ μs
FPBW	Full Power Bandwidth (Note 9)	$V_S = 5\text{V}, V_{\text{OUT}} = 3V_{\text{P-P}}$ (LT6200)	●	2.44	3.5	MHz

$T_A = 25^{\circ}\text{C}$, $V_S = \pm 5\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = 0\text{V}$, $V_{\text{SHDN}} = \text{OPEN}$, unless otherwise noted. Excludes the LT6201 in the DD package (Note 3).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{\text{CM}} = \text{Half Supply}$		1.4	4	mV
		$V_{\text{CM}} = V^+$		2.5	6	mV
		$V_{\text{CM}} = V^-$		2.5	6	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = 0\text{V}$ $V_{\text{CM}} = V^- \text{ to } V^+$		0.2 0.4	1.6 3.2	mV mV

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ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = 0\text{V}$, $V_{\text{SHDN}} = \text{OPEN}$, unless otherwise noted.
Excludes the LT6201 in the DD package (Note 3).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
I_B	Input Bias Current	$V_{\text{CM}} = \text{Half Supply}$ $V_{\text{CM}} = V^+$ $V_{\text{CM}} = V^-$	-40 -50	-10 8 -23	18	μA μA μA
ΔI_B	I_B Shift	$V_{\text{CM}} = V^- \text{ to } V^+$		31	68	μA
	I_B Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = V^- \text{ to } V^+$		0.2	6	μA
I_{OS}	Input Offset Current	$V_{\text{CM}} = \text{Half Supply}$ $V_{\text{CM}} = V^+$ $V_{\text{CM}} = V^-$		1.3 1 3	7 7 12	μA μA μA
	Input Noise Voltage	0.1Hz to 10Hz		600		nV _{p-p}
e_n	Input Noise Voltage Density	$f = 100\text{kHz}$ $f = 10\text{kHz}$		0.95 1.4	2.3	nV/ $\sqrt{\text{Hz}}$ nV/ $\sqrt{\text{Hz}}$
i_n	Input Noise Current Density, Balanced Source Unbalanced Source	$f = 10\text{kHz}$ $f = 10\text{kHz}$		2.2 3.5		pA/ $\sqrt{\text{Hz}}$ pA/ $\sqrt{\text{Hz}}$
	Input Resistance	Common Mode Differential Mode		0.57 2.1		M Ω k Ω
C_{IN}	Input Capacitance	Common Mode Differential Mode		3.1 4.2		pF pF
A_{VOL}	Large-Signal Gain	$V_O = \pm 4.5\text{V}$, $R_L = 1\text{k}$ $V_O = \pm 2\text{V}$, $R_L = 100$	115 15	200 26		V/mV V/mV
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = V^- \text{ to } V^+$ $V_{\text{CM}} = -2\text{V to } 2\text{V}$	68 75	96 100		dB dB
	CMRR Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = -2\text{V to } 2\text{V}$	80	105		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.25\text{V to } \pm 5\text{V}$	60	68		dB
	PSRR Match (Channel-to-Channel) (Note 6)	$V_S = \pm 1.25\text{V to } \pm 5\text{V}$	65	100		dB
V_{OL}	Output Voltage Swing LOW (Note 7)	No Load $I_{\text{SINK}} = 5\text{mA}$ $I_{\text{SINK}} = 20\text{mA}$		12 55 150	50 110 290	mV mV mV
V_{OH}	Output Voltage Swing HIGH (Note 7)	No Load $I_{\text{SOURCE}} = 5\text{mA}$ $I_{\text{SOURCE}} = 20\text{mA}$		70 110 225	130 210 420	mV mV mV
I_{SC}	Short-Circuit Current		± 60	± 90		mA
I_S	Supply Current per Amplifier Disabled Supply Current per Amplifier	$V_{\text{SHDN}} = 0.3\text{V}$		20 1.6	23 2.1	mA mA
I_{SHDN}	SHDN Pin Current	$V_{\text{SHDN}} = 0.3\text{V}$		200	280	μA
V_L	V_{SHDN} Pin Input Voltage LOW				0.3	V
V_H	V_{SHDN} Pin Input Voltage HIGH		$V^+ - 0.5$			V
	Shutdown Output Leakage Current	$V_{\text{SHDN}} = 0.3\text{V}$		0.1	75	μA
t_{ON}	Turn-On Time	$V_{\text{SHDN}} = 0.3\text{V to } 4.5\text{V}$, $R_L = 100\Omega$, $V_S = 5\text{V}$		180		ns
t_{OFF}	Turn-Off Time	$V_{\text{SHDN}} = 4.5\text{V to } 0.3\text{V}$, $R_L = 100\Omega$, $V_S = 5\text{V}$		180		ns
GBW	Gain Bandwidth Product	Frequency = 1MHz LT6200, LT6201 LT6200-5 LT6200-10	110 530 1060	165 800 1600		MHz MHz MHz
SR	Slew Rate	$A_V = -1$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200, LT6201 $A_V = -10$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200-5 LT6200-10	35 175 315	50 250 450		V/ μs V/ μs V/ μs

LT6200/LT6200-5 LT6200-10/LT6201

ELECTRICAL CHARACTERISTICS $T_A = 25^\circ\text{C}$, $V_S = \pm 5\text{V}$, $V_{CM} = V_{OUT} = 0\text{V}$, $V_{SHDN} = \text{OPEN}$, unless otherwise noted. Excludes the LT6201 in the DD package (Note 3).

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
FPBW	Full Power Bandwidth (Note 9)	$V_{OUT} = 3V_{P-P}$ (LT6200-10)	33	47		MHz
t_S	Setting Time (LT6200, LT6201)	0.1%, $V_{STEP} = 1$, $R_L = 1\text{k}$		140		ns

The ● denotes the specifications which apply over $0^\circ\text{C} < T_A < 70^\circ\text{C}$ temperature range. Excludes the LT6201 in the DD package (Note 3). $V_S = \pm 5\text{V}$, $V_{CM} = V_{OUT} = 0\text{V}$, $V_{SHDN} = \text{OPEN}$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{CM} = \text{Half Supply}$	●	1.9	4.5	mV
		$V_{CM} = V^+$	●	3.5	7.5	mV
		$V_{CM} = V^-$	●	3.5	7.5	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	$V_{CM} = 0\text{V}$	●	0.2	1.8	mV
		$V_{CM} = V^- \text{ to } V^+$	●	0.4	3.4	mV
$V_{OS\ TC}$	Input Offset Voltage Drift (Note 8)	$V_{CM} = \text{Half Supply}$	●	8.2	24	$\mu\text{V}/^\circ\text{C}$
I_B	Input Bias Current	$V_{CM} = \text{Half Supply}$	●	-40	-10	μA
		$V_{CM} = V^+$	●		8	μA
		$V_{CM} = V^-$	●	-50	-23	μA
ΔI_B	I_B Shift	$V_{CM} = V^- \text{ to } V^+$	●	31	68	μA
	I_B Match (Channel-to-Channel) (Note 11)	$V_{CM} = V^- \text{ to } V^+$	●	1	9	μA
I_{OS}	Input Offset Current	$V_{CM} = \text{Half Supply}$	●	1.3	10	μA
		$V_{CM} = V^+$	●	1	10	μA
		$V_{CM} = V^-$	●	3.5	15	μA
A_{VOL}	Large-Signal Gain	$V_O = \pm 4.5\text{V}$, $R_L = 1\text{k}$	●	46	80	V/mV
		$V_O = \pm 2\text{V}$, $R_L = 100$	●	7.5	13.5	V/mV
CMRR	Common Mode Rejection Ratio	$V_{CM} = V^- \text{ to } V^+$	●	65	90	dB
		$V_{CM} = -2\text{V} \text{ to } 2\text{V}$	●	75	100	dB
	CMRR Match (Channel-to-Channel) (Note 11)	$V_{CM} = -2\text{V} \text{ to } 2\text{V}$	●	75	105	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.5\text{V} \text{ to } \pm 5\text{V}$	●	60	65	dB
		PSRR Match (Channel-to-Channel) (Note 6)	●	60	100	dB
V_{OL}	Output Voltage Swing LOW (Note 7)	No Load	●	16	70	mV
		$I_{SINK} = 5\text{mA}$	●	60	120	mV
		$I_{SINK} = 20\text{mA}$	●	170	310	mV
V_{OH}	Output Voltage Swing HIGH (Note 7)	No Load	●	85	150	mV
		$I_{SOURCE} = 5\text{mA}$	●	125	230	mV
		$I_{SOURCE} = 20\text{mA}$	●	265	480	mV
I_{SC}	Short-Circuit Current		●	± 60	± 90	mA
I_S	Supply Current per Amplifier Disabled Supply Current per Amplifier	$V_{SHDN} = 0.3\text{V}$	●	25	29	mA
			●	1.6	2.1	mA
I_{SHDN}	SHDN Pin Current	$V_{SHDN} = 0.3\text{V}$	●	215	295	μA
V_L	V_{SHDN} Pin Input Voltage LOW		●		0.3	V
V_H	V_{SHDN} Pin Input Voltage HIGH		●	$V^+ - 0.5$		V
	Shutdown Output Leakage Current	$V_{SHDN} = 0.3\text{V}$	●	0.1	75	μA
t_{ON}	Turn-On Time	$V_{SHDN} = 0.3\text{V} \text{ to } 4.5\text{V}$, $R_L = 100\Omega$, $V_S = 5\text{V}$	●	180		ns
t_{OFF}	Turn-Off Time	$V_{SHDN} = 4.5\text{V} \text{ to } 0.3\text{V}$, $R_L = 100\Omega$, $V_S = 5\text{V}$	●	180		ns
SR	Slew Rate	$A_V = -1$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200, LT6201	●	31	44	V/ μs
		$A_V = -10$, $R_L = 1\text{k}$, $V_O = 4\text{V}$ LT6200-5 LT6200-10	●	150	215	V/ μs
FPBW	Full Power Bandwidth (Note 9)	$V_{OUT} = 3V_{P-P}$ (LT6200-10)	●	30	43	MHz

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ELECTRICAL CHARACTERISTICS The ● denotes the specifications which apply over $-40^{\circ}\text{C} < T_A < 85^{\circ}\text{C}$ temperature range. Excludes the LT6201 in the DD package (Note 3). $V_S = \pm 5\text{V}$, $V_{\text{CM}} = V_{\text{OUT}} = 0\text{V}$, $V_{\text{SHDN}} = \text{OPEN}$, unless otherwise noted. (Note 5)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
V_{OS}	Input Offset Voltage	$V_{\text{CM}} = \text{Half Supply}$	●	1.9	4.5	mV
		$V_{\text{CM}} = V^+$	●	3.5	7.5	mV
		$V_{\text{CM}} = V^-$	●	3.5	7.5	mV
	Input Offset Voltage Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = 0\text{V}$	●	0.2	2	mV
		$V_{\text{CM}} = V^- \text{ to } V^+$	●	0.4	3.6	mV
$V_{\text{OS TC}}$	Input Offset Voltage Drift (Note 8)	$V_{\text{CM}} = \text{Half Supply}$	●	8.2	24	$\mu\text{V}/^{\circ}\text{C}$
I_{B}	Input Bias Current	$V_{\text{CM}} = \text{Half Supply}$	●	-40	-10	μA
		$V_{\text{CM}} = V^+$	●		8	μA
		$V_{\text{CM}} = V^-$	●	-50	-23	μA
ΔI_{B}	I_{B} Shift	$V_{\text{CM}} = V^- \text{ to } V^+$	●	31	68	μA
	I_{B} Match (Channel-to-Channel) (Note 11)		●	4	12	μA
I_{OS}	Input Offset Current	$V_{\text{CM}} = \text{Half Supply}$	●	1.3	10	μA
		$V_{\text{CM}} = V^+$	●	1	10	μA
		$V_{\text{CM}} = V^-$	●	3.5	15	μA
A_{VOL}	Large-Signal Gain	$V_{\text{O}} = \pm 4.5\text{V}$, $R_{\text{L}} = 1\text{k}$	●	46	80	V/mV
		$V_{\text{O}} = \pm 2\text{V}$, $R_{\text{L}} = 100$	●	7.5	13.5	V/mV
CMRR	Common Mode Rejection Ratio	$V_{\text{CM}} = V^- \text{ to } V^+$	●	65	90	dB
		$V_{\text{CM}} = -2\text{V} \text{ to } 2\text{V}$	●	75	100	dB
	CMRR Match (Channel-to-Channel) (Note 11)	$V_{\text{CM}} = -2\text{V} \text{ to } 2\text{V}$	●	75	105	dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.5\text{V} \text{ to } \pm 5\text{V}$	●	60	65	dB
		PSRR Match (Channel-to-Channel) (Note 6)	●	60	100	dB
V_{OL}	Output Voltage Swing LOW (Note 7)	No Load	●	16	75	mV
		$I_{\text{SINK}} = 5\text{mA}$	●	60	125	mV
		$I_{\text{SINK}} = 20\text{mA}$	●	170	310	mV
V_{OH}	Output Voltage Swing HIGH (Note 7)	No Load	●	85	150	mV
		$I_{\text{SOURCE}} = 5\text{mA}$	●	125	230	mV
		$I_{\text{SINK}} = 20\text{mA}$	●	265	480	mV
I_{SC}	Short-Circuit Current		●	± 60	± 90	mA
I_{S}	Supply Current		●	25	29	mA
	Disabled Supply Current	$V_{\text{SHDN}} = 0.3\text{V}$	●	1.6	2.1	mA
I_{SHDN}	SHDN Pin Current	$V_{\text{SHDN}} = 0.3\text{V}$	●	215	295	μA
V_{L}	V_{SHDN} Pin Input Voltage LOW		●		0.3	V
V_{H}	V_{SHDN} Pin Input Voltage HIGH		●	$V^+ - 0.5$		V
	Shutdown Output Leakage Current	$V_{\text{SHDN}} = 0.3\text{V}$	●	0.1	75	μA
t_{ON}	Turn-On Time	$V_{\text{SHDN}} = 0.3\text{V} \text{ to } 4.5\text{V}$, $R_{\text{L}} = 100\Omega$, $V_S = 5\text{V}$	●	180		ns
t_{OFF}	Turn-Off Time	$V_{\text{SHDN}} = 4.5\text{V} \text{ to } 0.3\text{V}$, $R_{\text{L}} = 100\Omega$, $V_S = 5\text{V}$	●	180		ns
SR	Slew Rate	$A_{\text{V}} = -1$, $R_{\text{L}} = 1\text{k}$, $V_{\text{O}} = 4\text{V}$ LT6200, LT6201	●	31	44	V/ μs
		$A_{\text{V}} = -10$, $R_{\text{L}} = 1\text{k}$, $V_{\text{O}} = 4\text{V}$ LT6200-5 LT6200-10	● ●	125 260	180 370	V/ μs V/ μs
FPBW	Full Power Bandwidth (Note 9)	$V_{\text{OUT}} = 3\text{V}_{\text{P-P}}$ (LT6200-10)	●	27	39	MHz

Note 1: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. Exposure to any Absolute Maximum Rating condition for extended periods may affect device reliability and lifetime

Note 2: Inputs are protected by back-to-back diodes. If the differential input voltage exceeds 0.7V, the input current must be limited to less than 40mA. This parameter is guaranteed to meet specified performance through design and/or characterization. It is not 100% tested.

ELECTRICAL CHARACTERISTICS

Note 3: A heat sink may be required to keep the junction temperature below the absolute maximum rating when the output is shorted indefinitely. The LT6201 in the DD package is limited by power dissipation to $V_S \leq 5V, 0V$ over the commercial temperature range only.

Note 4: The LT6200C/LT6200I and LT6201C/LT6201I are guaranteed functional over the temperature range of -40°C and 85°C (LT6201DD excluded).

Note 5: The LT6200C/LT6201C are guaranteed to meet specified performance from 0°C to 70°C . The LT6200C/LT6201C are designed, characterized and expected to meet specified performance from -40°C to 85°C , but are not tested or QA sampled at these temperatures. The LT6200I is guaranteed to meet specified performance from -40°C to 85°C .

Note 6: Minimum supply voltage is guaranteed by power supply rejection ratio test.

Note 7: Output voltage swings are measured between the output and power supply rails.

Note 8: This parameter is not 100% tested.

Note 9: Full-power bandwidth is calculated from the slew rate:
$$FPBW = SR/2\pi V_P$$

Note 10: Thermal resistance varies depending upon the amount of PC board metal attached to the V^- pin of the device. θ_{JA} is specified for a certain amount of 2oz copper metal trace connecting to the V^- pin as described in the thermal resistance tables in the Application Information section.

Note 11: Matching parameters on the LT6201 are the difference between the two amplifiers. CMRR and PSRR match are defined as follows: CMRR and PSRR are measured in $\mu\text{V/V}$ on the identical amplifiers. The difference is calculated in $\mu\text{V/V}$. The result is converted to dB.

Note 12: There are reverse biased ESD diodes on all inputs and outputs, as shown in Figure 1. If these pins are forced beyond either supply, unlimited current will flow through these diodes. If the current is transient in nature and limited to less than 30mA, no damage to the device will occur.

TYPICAL PERFORMANCE CHARACTERISTICS

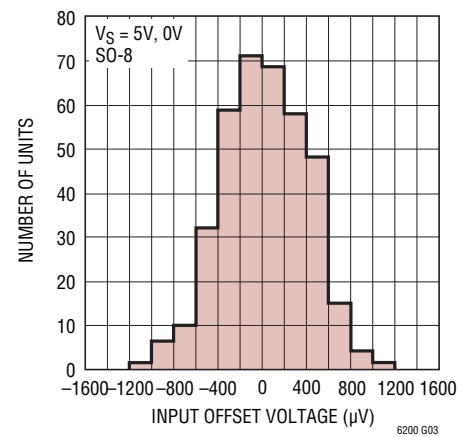
V_{OS} Distribution, $V_{CM} = V^+/2$



V_{OS} Distribution, $V_{CM} = V^+$



V_{OS} Distribution, $V_{CM} = V^-$



Supply Current vs Supply Voltage



Offset Voltage vs Input Common Mode Voltage



Input Bias Current vs Common Mode Voltage



TYPICAL PERFORMANCE CHARACTERISTICS

Input Bias Current vs Temperature



6200 G07

Output Saturation Voltage vs Load Current (Output Low)



6200 G08

Output Saturation Voltage vs Load Current (Output High)



6200 G09

Minimum Supply Voltage



6200 G10

Output Short-Circuit Current vs Power Supply Voltage



6200 G11

Open-Loop Gain



6200 G12

Open-Loop Gain



6200 G13

Open-Loop Gain



6200 G14

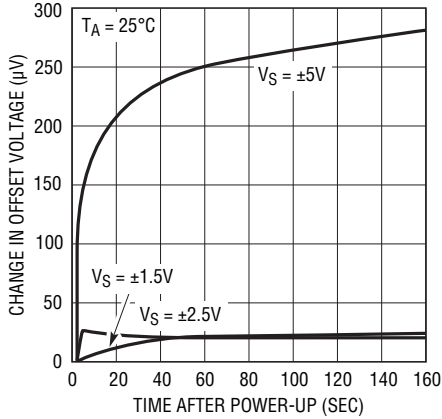
Offset Voltage vs Output Current



6200 G15

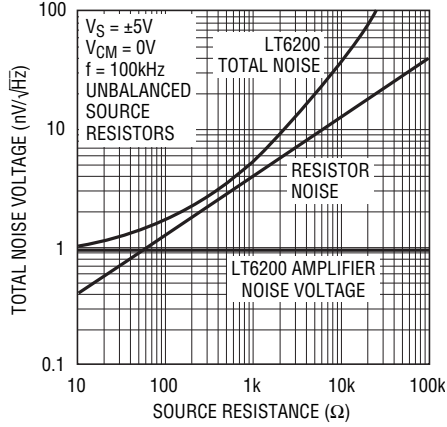
TYPICAL PERFORMANCE CHARACTERISTICS

Warm-Up Drift vs Time (LT6200S8)



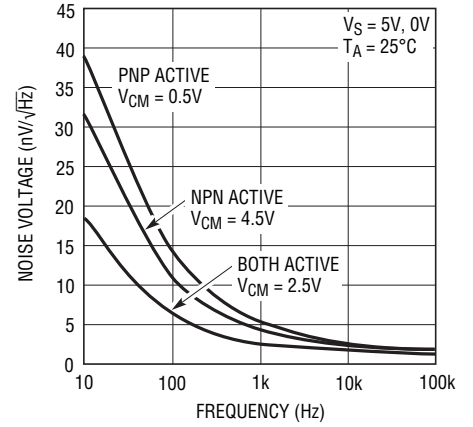
6200 G16

Total Noise vs Source Resistance



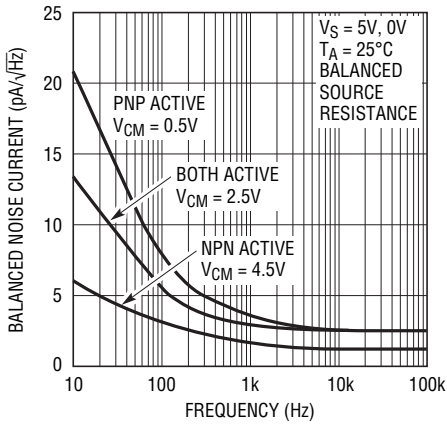
6200 G17

Input Noise Voltage vs Frequency



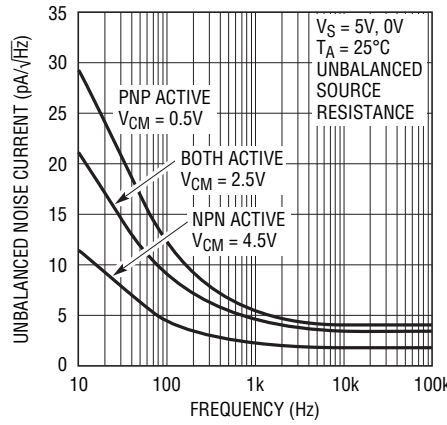
6200 G18

Balanced Noise Current vs Frequency



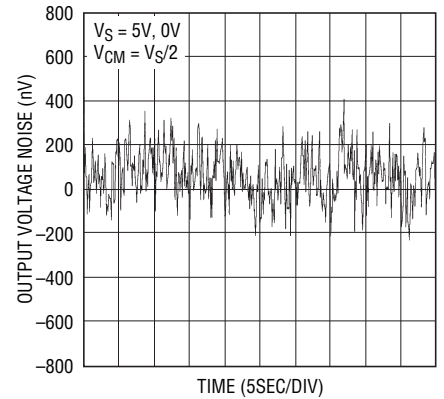
6200 G19

Unbalanced Noise Current vs Frequency



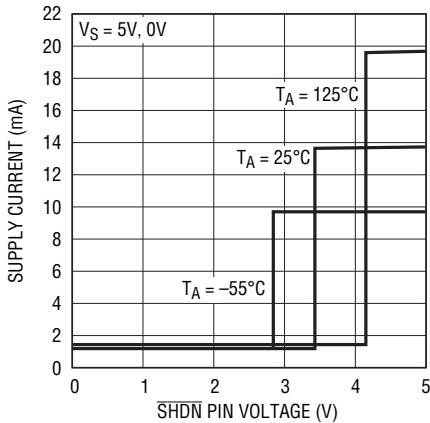
6200 G20

0.1Hz to 10Hz Output Noise Voltage



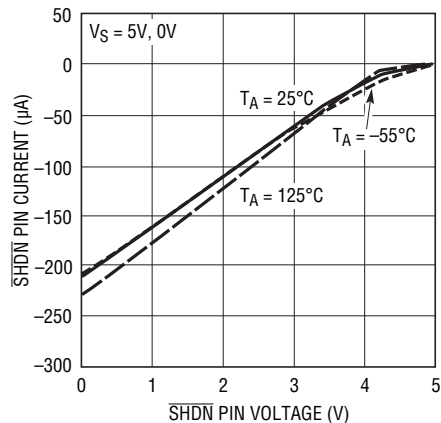
6200 G21

Supply Current vs SHDN Pin Voltage



6200 G21a

SHDN Pin Current vs SHDN Pin Voltage



6200 G21b

TYPICAL PERFORMANCE CHARACTERISTICS LT6200, LT6201

Gain Bandwidth and Phase Margin vs Temperature



6200 G22

Open-Loop Gain vs Frequency



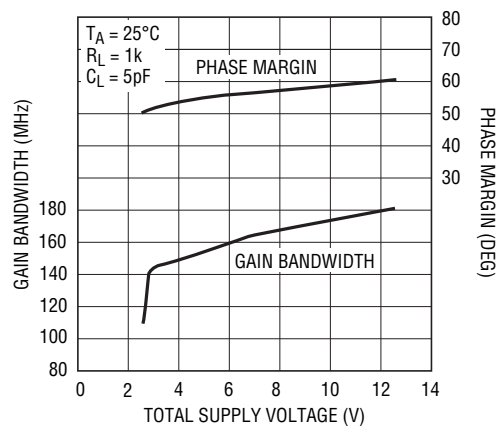
6200 G23

Open-Loop Gain vs Frequency



6200 G24

Gain Bandwidth and Phase Margin vs Supply Voltage



6200 G25

Slew Rate vs Temperature



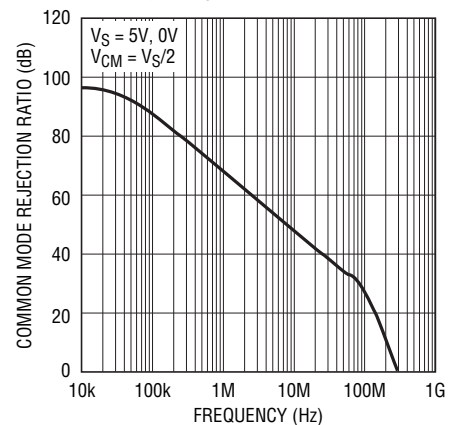
6200 G26

Output Impedance vs Frequency



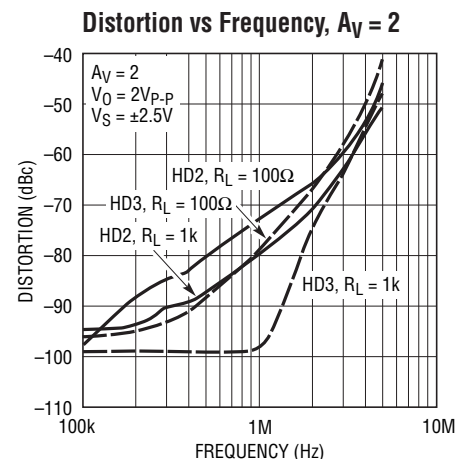
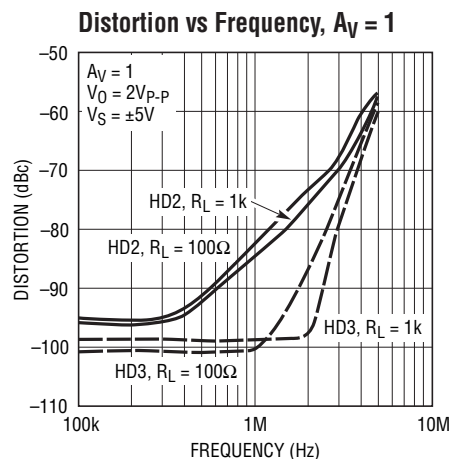
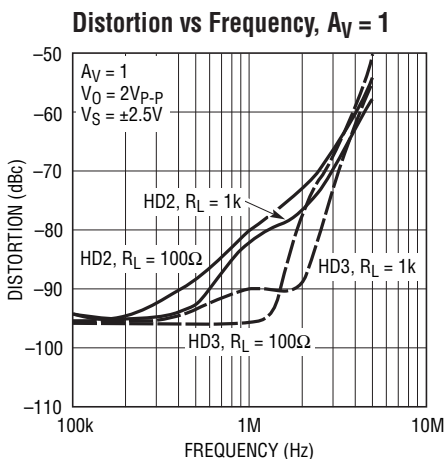
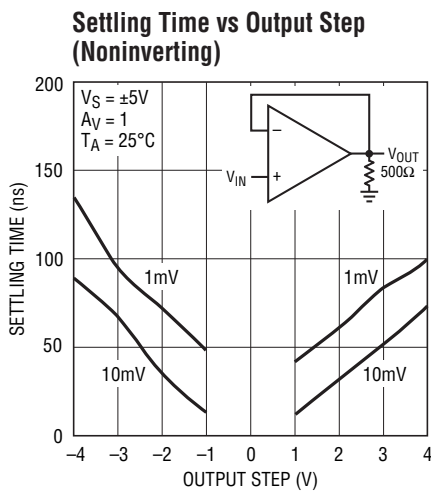
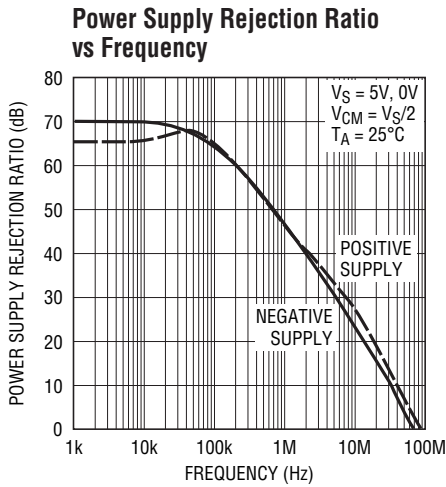
6200 G27

Common Mode Rejection Ratio vs Frequency

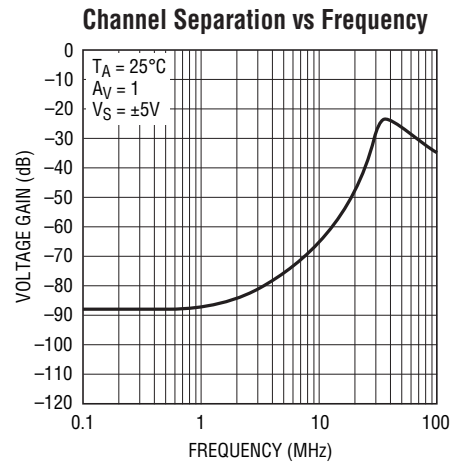


6200 G28

TYPICAL PERFORMANCE CHARACTERISTICS LT6200, LT6201

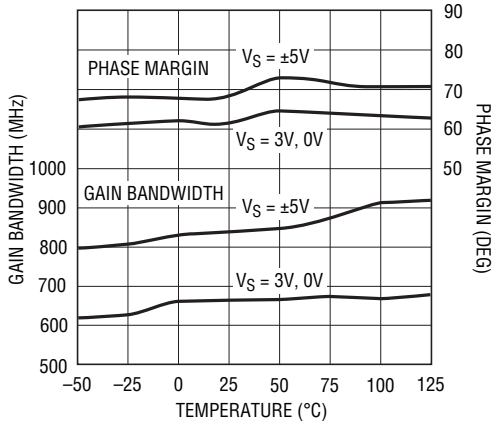


TYPICAL PERFORMANCE CHARACTERISTICS LT6200, LT6201



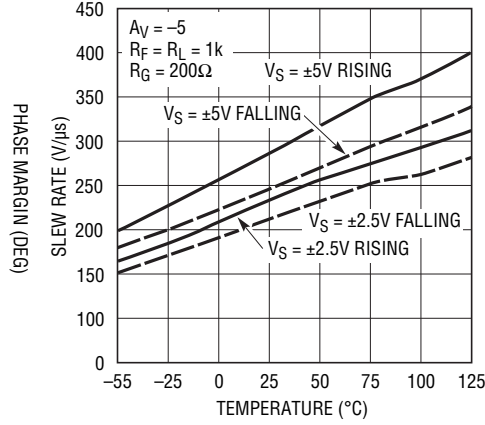
TYPICAL PERFORMANCE CHARACTERISTICS LT6200-5

Gain Bandwidth and Phase Margin vs Temperature



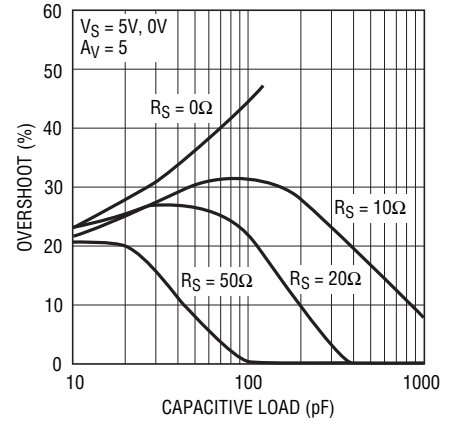
6200 G45

Slew Rate vs Temperature



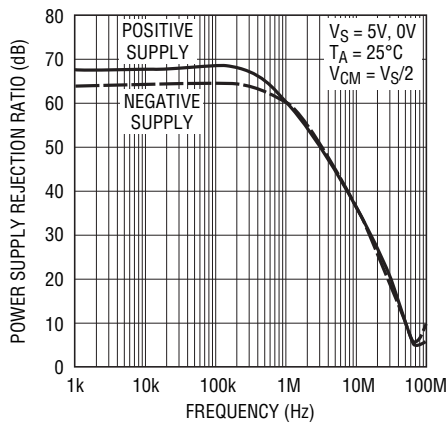
6200 G46

Overshoot vs Capacitive Load



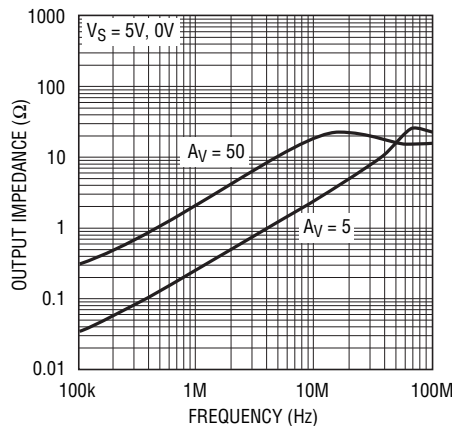
6200 G47

Power Supply Rejection Ratio vs Frequency



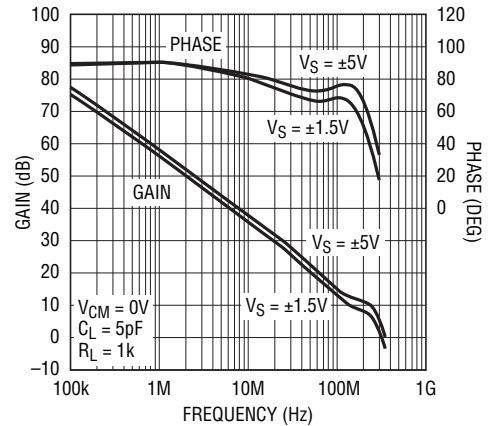
6200 G48

Output Impedance vs Frequency



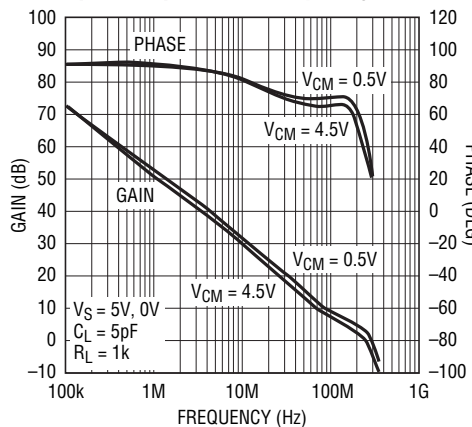
6200 G49

Open-Loop Gain vs Frequency



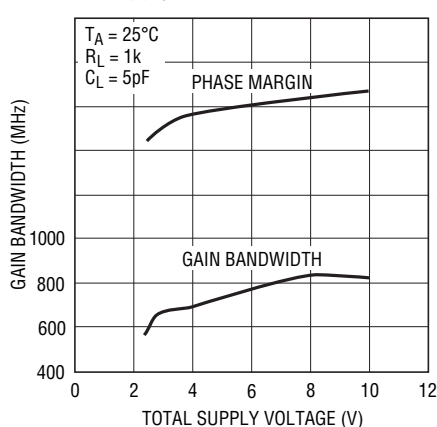
6200 G50

Open-Loop Gain vs Frequency



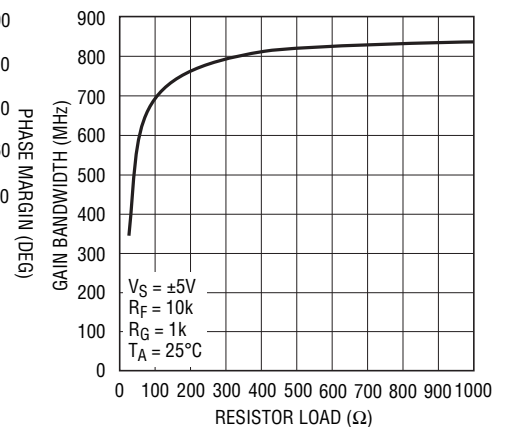
6200 G51

Gain Bandwidth and Phase Margin vs Supply Voltage



6200 G52

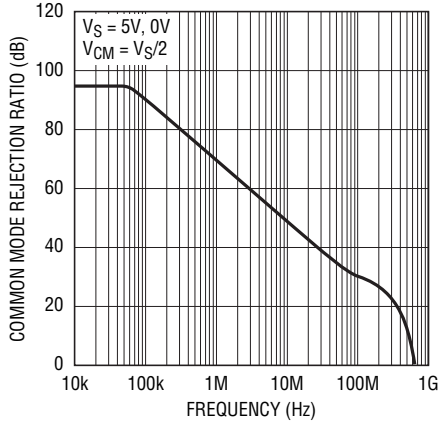
Gain Bandwidth vs Resistor Load



6200 G53

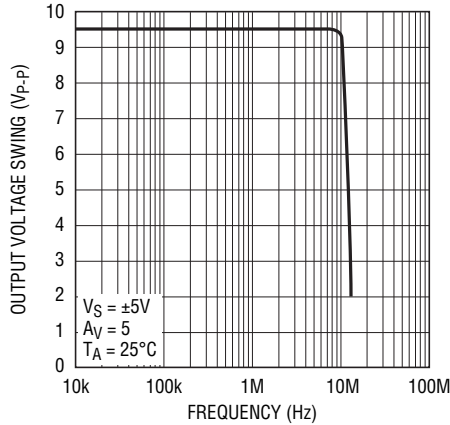
TYPICAL PERFORMANCE CHARACTERISTICS LT6200-5

Common Mode Rejection Ratio vs Frequency



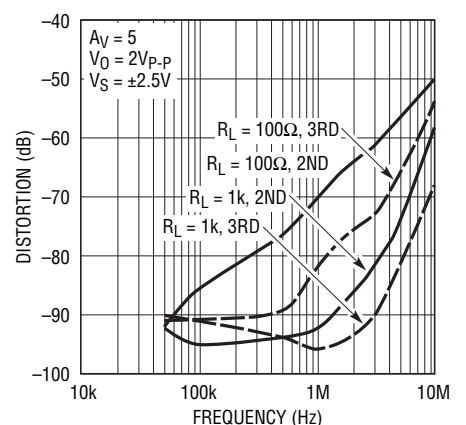
6200 G54

Maximum Undistorted Output Signal vs Frequency



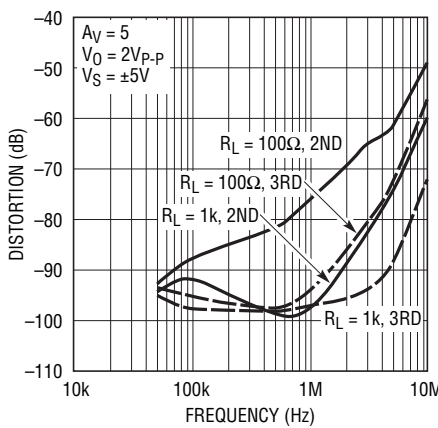
6200 G55

2nd and 3rd Harmonic Distortion vs Frequency



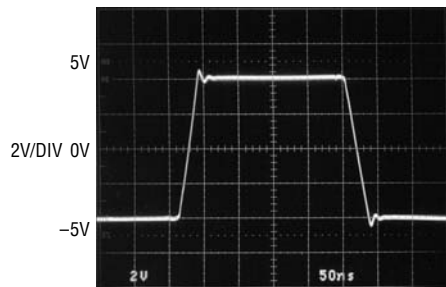
6200 G56

2nd and 3rd Harmonic Distortion vs Frequency



6200 G57

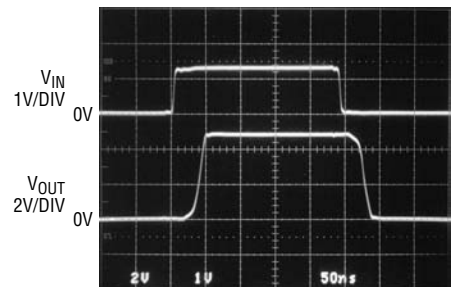
±5V Large-Signal Response



VS = ±5V
AV = 5
RL = 1k
CL = 10.8pF SCOPE PROBE

6200 G58

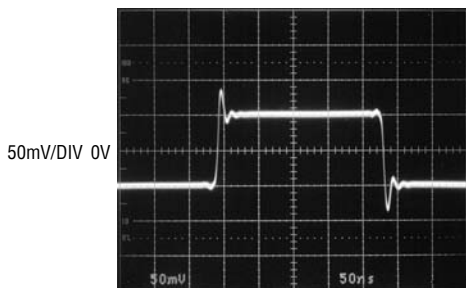
Output-Overdrive Recovery



VS = 5V, 0V
AV = 5
CL = 10.8pF SCOPE PROBE

6200 G59

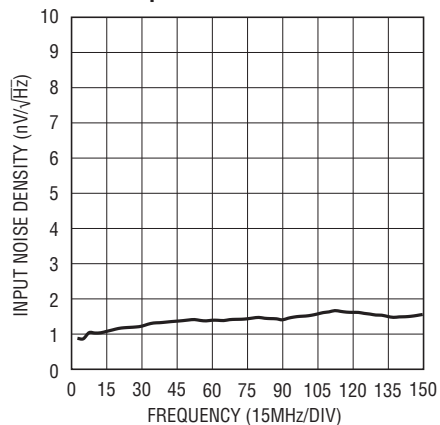
5V Small-Signal Response



VS = 5V, 0V
AV = 5
RL = 1k
CL = 10.8pF SCOPE PROBE

6200 G60

Input Referred High Frequency Noise Spectrum



6200 G61

TYPICAL PERFORMANCE CHARACTERISTICS LT6200-10

Gain Bandwidth and Phase Margin vs Temperature



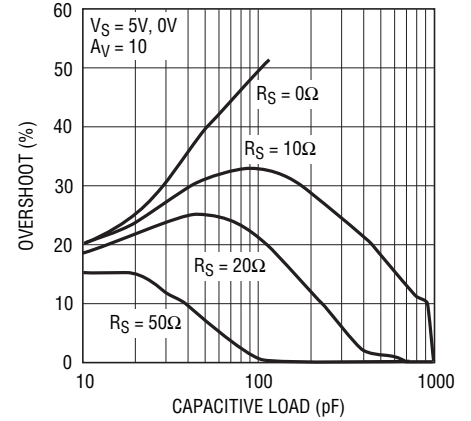
6200 G62

Slew Rate vs Temperature



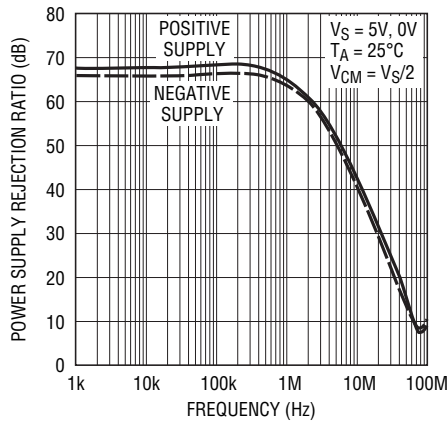
6200 G63

Overshoot vs Capacitive Load



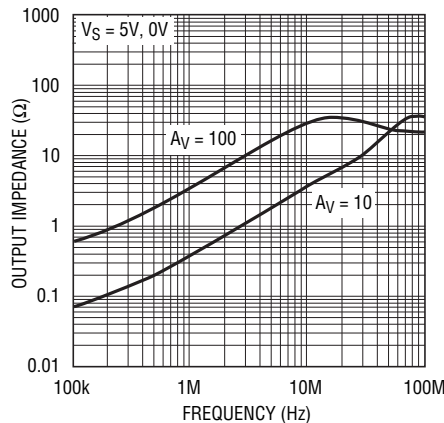
6200 G64

Power Supply Rejection Ratio vs Frequency



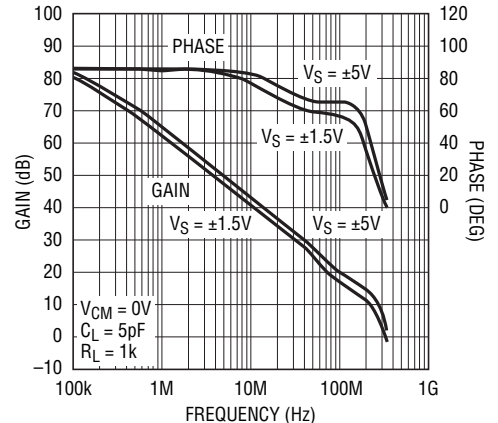
6200 G65

Output Impedance vs Frequency



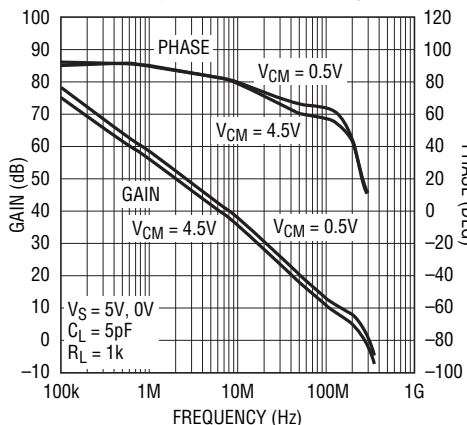
6200 G66

Open-Loop Gain vs Frequency



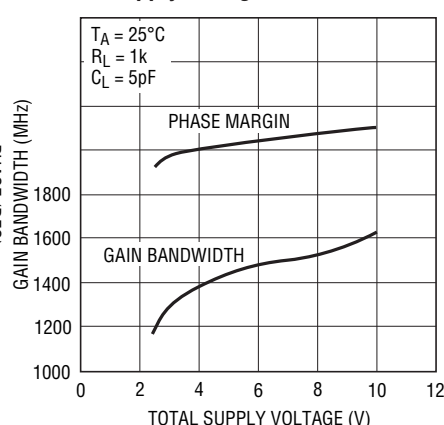
6200 G67

Open-Loop Gain vs Frequency



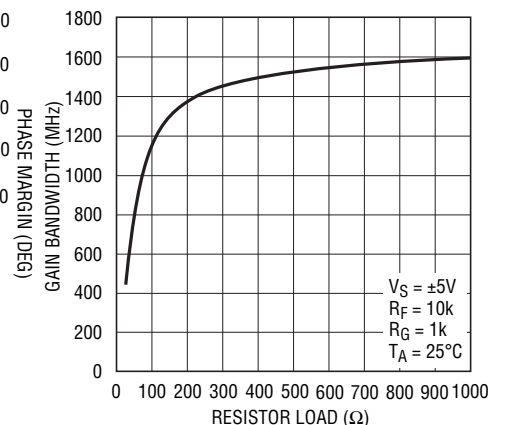
6200 G68

Gain Bandwidth and Phase Margin vs Supply Voltage



6200 G69

Gain Bandwidth vs Resistor Load



6200 G70

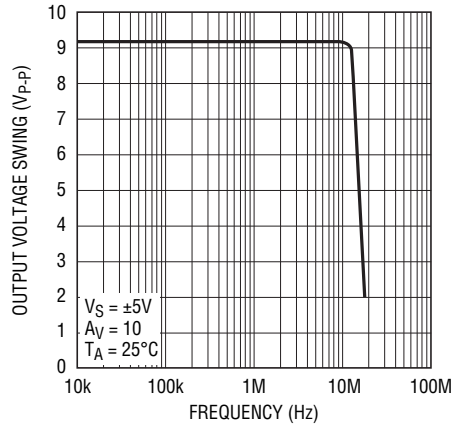
620011f

TYPICAL PERFORMANCE CHARACTERISTICS LT6200-10

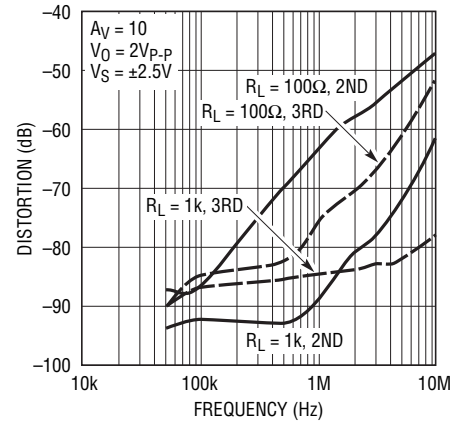
Common Mode Rejection Ratio vs Frequency



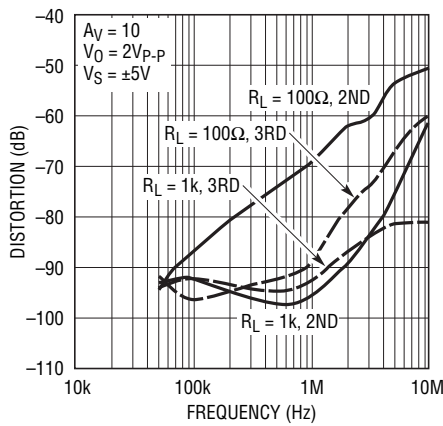
Maximum Undistorted Output Signal vs Frequency



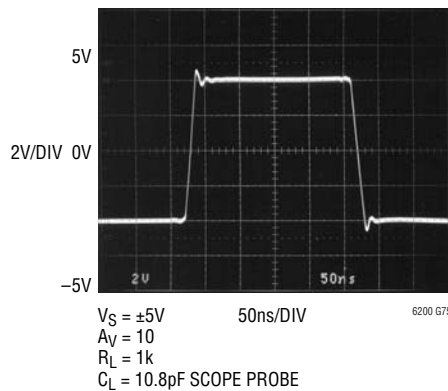
2nd and 3rd Harmonic Distortion vs Frequency



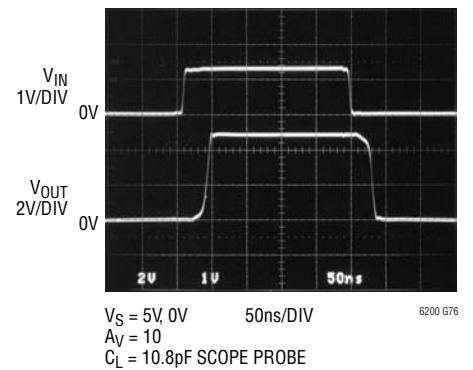
2nd and 3rd Harmonic Distortion vs Frequency



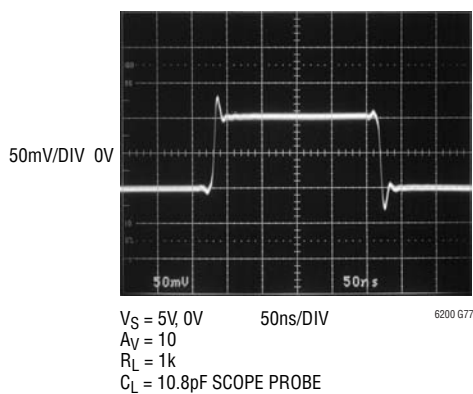
±5V Large-Signal Response



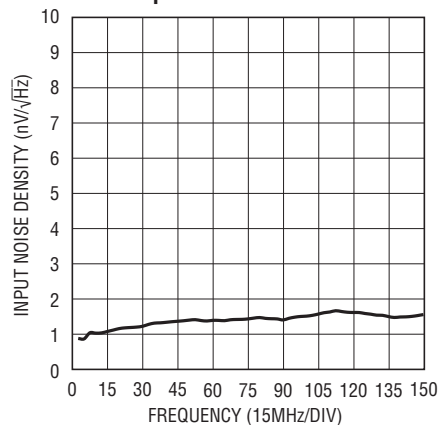
Output-Overdrive Recovery



5V Small-Signal Response



Input Referred High Frequency Noise Spectrum



APPLICATIONS INFORMATION

Amplifier Characteristics

Figure 1 shows a simplified schematic of the LT6200 family, which has two input differential amplifiers in parallel that are biased on simultaneously when the common mode voltage is at least 1.5V from either rail. This topology allows the input stage to swing from the positive supply voltage to the negative supply voltage. As the common mode voltage swings beyond $V_{CC} - 1.5V$, current source I_1 saturates and current in Q1/Q4 is zero. Feedback is maintained through the Q2/Q3 differential amplifier, but with an input g_m reduction of one-half. A similar effect occurs with I_2 when the common mode voltage swings within 1.5V of the negative rail. The effect of the g_m reduction is a shift in the V_{OS} as I_1 or I_2 saturate.

Input bias current normally flows out of the “+” and “-” inputs. The magnitude of this current increases when the input common mode voltage is within 1.5V of the negative rail, and only Q1/Q4 are active. The polarity of this current reverses when the input common mode voltage is within 1.5V of the positive rail and only Q2/Q3 are active.

The second stage is a folded cascode and current mirror that converts the input stage differential signals to a single ended output. Capacitor C1 reduces the unity cross frequency and improves the frequency stability without degrading the gain bandwidth of the amplifier. The differential drive generator supplies current to the output transistors that swing from rail-to-rail.

The LT6200-5/LT6200-10 are decompensated op amps for higher gain applications. These amplifiers maintain identical DC specifications with the LT6200, but have a reduced Miller compensation capacitor C_M . This results in a significantly higher slew rate and gain bandwidth product.

Input Protection

There are back-to-back diodes, D1 and D2, across the + and - inputs of these amplifiers to limit the differential input voltage to $\pm 0.7V$. The inputs of the LT6200 family do not have internal resistors in series with the input transistors. This technique is often used to protect the input devices from overvoltage that causes excessive currents to flow. The addition of these resistors would significantly degrade the low noise voltage of these amplifiers. For instance, a 100Ω resistor in series with each input would generate $1.8nV/\sqrt{Hz}$ of noise, and the total amplifier noise voltage would rise from $0.95nV/\sqrt{Hz}$ to $2.03nV/\sqrt{Hz}$. Once the input differential voltage exceeds $\pm 0.7V$, steady-state current conducted through the protection diodes should be limited to $\pm 40mA$. This implies 25Ω of protection resistance per volt of continuous overdrive beyond $\pm 0.7V$. The input diodes are rugged enough to handle transient currents due to amplifier slew rate overdrive or momentary clipping without these resistors.

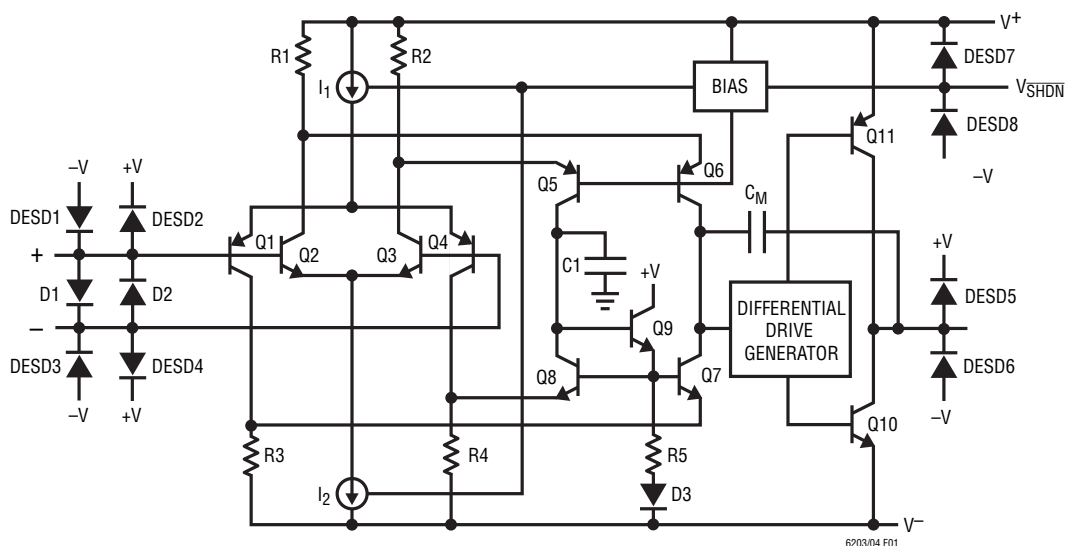


Figure 1. Simplified Schematic

APPLICATIONS INFORMATION

Figure 2 shows the input and output waveforms of the LT6200 driven into clipping while connected in a gain of $A_V = 1$. In this photo, the input signal generator is clipping at $\pm 35\text{mA}$, and the output transistors supply this generator current through the protection diodes.



Figure 2. $V_S = \pm 2.5\text{V}$, $A_V = 1$ with Large Overdrive

ESD

The LT6200 has reverse-biased ESD protection diodes on all inputs and outputs, as shown in Figure 1. If these pins are forced beyond either supply, unlimited current will flow through these diodes. If the current is transient and limited to 30mA or less, no damage to the device will occur.

Noise

The noise voltage of the LT6200 is equivalent to that of a 56Ω resistor—and for the lowest possible noise, it is desirable to keep the source and feedback resistance at or below this value (i.e., $R_S + R_G//R_{FB} \leq 56\Omega$). With $R_S + R_G//R_{FB} = 56\Omega$ the total noise of the amplifier is: $e_n = \sqrt{(0.95\text{nV})^2 + (0.95\text{nV})^2} = 1.35\text{nV}$. Below this resistance value the amplifier dominates the noise, but in the resistance region between 56Ω and approximately $6\text{k}\Omega$, the noise is dominated by the resistor thermal noise. As the total resistance is further increased, beyond $6\text{k}\Omega$, the noise current multiplied by the total resistance eventually dominates the noise.

For a complete discussion of amplifier noise, see the LT1028 data sheet.

Power Dissipation

The LT6200 combines high speed with large output current in a small package, so there is a need to ensure that the die's junction temperature does not exceed 150°C . The LT6200 is housed in a 6-lead TSOT-23 package. The package has the V^- supply pin fused to the lead frame to enhance the thermal conductance when connecting to a ground plane or a large metal trace. Metal trace and plated through-holes can be used to spread the heat generated by the device to the backside of the PC board. For example, on a $3/32"$ FR-4 board with 2oz copper, a total of 270mm^2 connects to Pin 2 of the LT6200 (in a TSOT-23 package) bringing the thermal resistance, θ_{JA} , to about $135^\circ\text{C}/\text{W}$. Without an extra metal trace beside the power line connecting to the V^- pin to provide a heat sink, the thermal resistance will be around $200^\circ\text{C}/\text{W}$. More information on thermal resistance with various metal areas connecting to the V^- pin is provided in Table 1.

Table 1. LT6200 6-Lead TSOT-23 Package

COPPER AREA TOPSIDE (mm^2)	BOARD AREA (mm^2)	THERMAL RESISTANCE (JUNCTION-TO-AMBIENT)
270	2500	$135^\circ\text{C}/\text{W}$
100	2500	$145^\circ\text{C}/\text{W}$
20	2500	$160^\circ\text{C}/\text{W}$
0	2500	$200^\circ\text{C}/\text{W}$

Device is mounted on topside.

Junction temperature T_J is calculated from the ambient temperature T_A and power dissipation P_D as follows:

$$T_J = T_A + (P_D \cdot \theta_{JA})$$

The power dissipation in the IC is the function of the supply voltage, output voltage and the load resistance. For a given supply voltage, the worst-case power dissipation $P_{D(\text{MAX})}$ occurs at the maximum quiescent supply current and at the output voltage which is half of either supply voltage (or the maximum swing if it is less than half the supply voltage). $P_{D(\text{MAX})}$ is given by:

$$P_{D(\text{MAX})} = (V_S \cdot I_{S(\text{MAX})}) + (V_S/2)^2/R_L$$

Example: An LT6200 in TSOT-23 mounted on a 2500mm^2 area of PC board without any extra heat spreading plane connected to its V^- pin has a thermal resistance of

APPLICATIONS INFORMATION

200°C/W, θ_{JA} . Operating on $\pm 5V$ supplies driving 50 Ω loads, the worst-case power dissipation is given by:

$$P_{D(MAX)} = (10 \cdot 23mA) + (2.5)^2/50 \\ = 0.23 + 0.125 = 0.355W$$

The maximum ambient temperature that the part is allowed to operate is:

$$T_A = T_J - (P_{D(MAX)} \cdot 200^\circ C/W) \\ = 150^\circ C - (0.355W \cdot 200^\circ C/W) = 79^\circ C$$

To operate the device at a higher ambient temperature, connect more metal area to the V^- pin to reduce the thermal resistance of the package, as indicated in Table 1.

DD Package Heat Sinking

The underside of the DD package has exposed metal (4mm²) from the lead frame where the die is attached. This provides for the direct transfer of heat from the die junction to printed circuit board metal to help control the maximum operating junction temperature. The dual-in-line pin arrangement allows for extended metal beyond the ends of the package on the topside (component side) of

a PCB. Table 2 summarizes the thermal resistance from the die junction-to-ambient that can be obtained using various amounts of topside metal (2oz copper) area. On multilayer boards, further reductions can be obtained using additional metal on inner PCB layers connected through vias beneath the package.

Table 2. LT6200 8-Lead DD Package

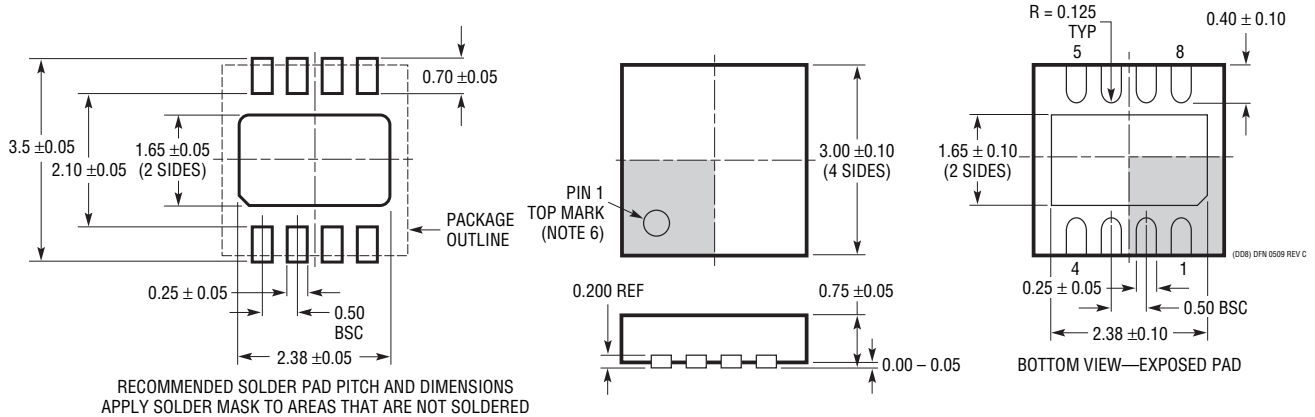
COPPER AREA TOPSIDE (mm ²)	THERMAL RESISTANCE (JUNCTION-TO-AMBIENT)
4	160°C/W
16	135°C/W
32	110°C/W
64	95°C/W
130	70°C/W

The LT6200 amplifier family has thermal shutdown to protect the part from excessive junction temperature. The amplifier will shut down to approximately 1.2mA supply current per amplifier if 160°C is exceeded. The LT6200 will remain off until the junction temperature reduces to about 150°C, at which point the amplifier will return to normal operation.

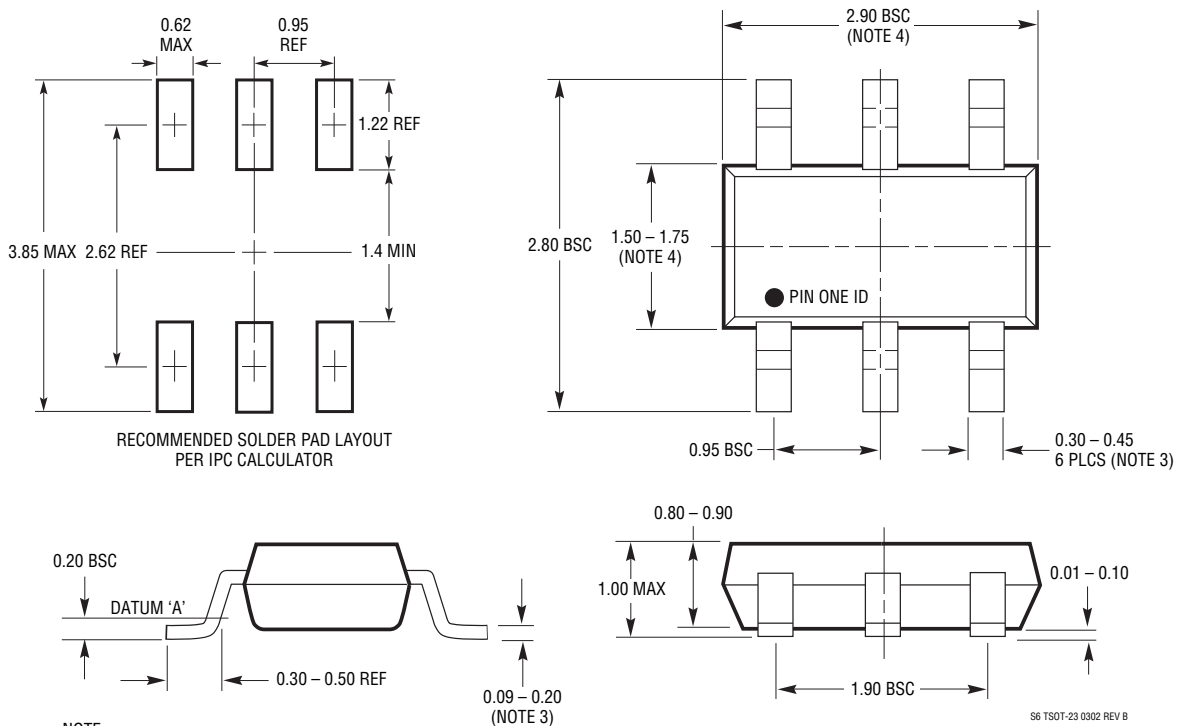
PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

DD Package 8-Lead Plastic DFN (3mm × 3mm) (Reference LTC DWG # 05-08-1698 Rev C)



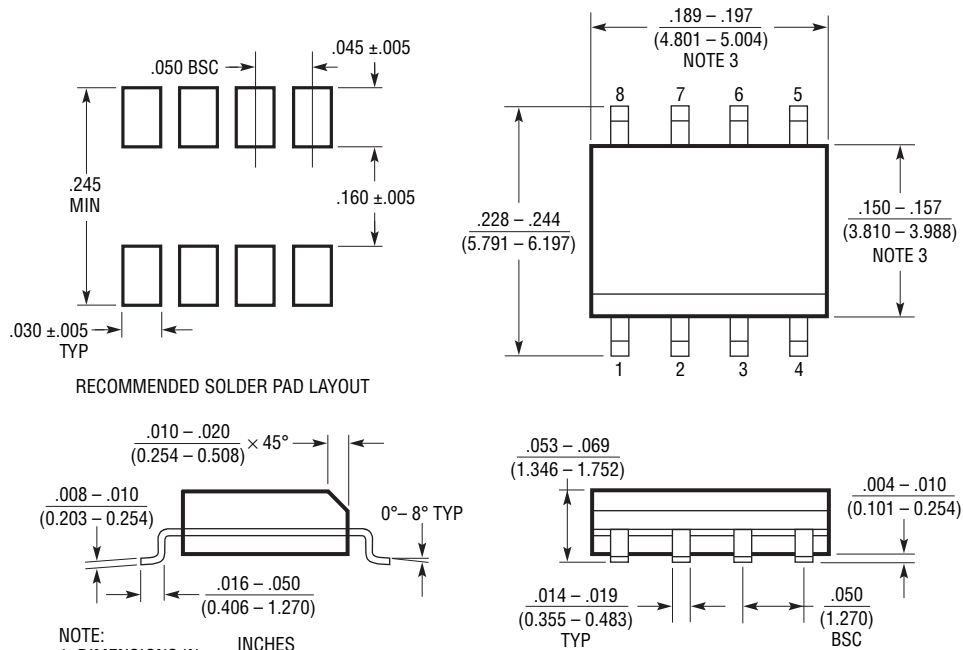
S6 Package 6-Lead Plastic TSOT-23 (Reference LTC DWG # 05-08-1636)



PACKAGE DESCRIPTION

Please refer to <http://www.linear.com/designtools/packaging/> for the most recent package drawings.

S8 Package 8-Lead Plastic Small Outline (Narrow .150 Inch) (Reference LTC DWG # 05-08-1610)



- NOTE:
 1. DIMENSIONS IN $\frac{\text{INCHES}}{\text{(MILLIMETERS)}}$
 2. DRAWING NOT TO SCALE
 3. THESE DIMENSIONS DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS.
 MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED $.006''$ (0.15mm)

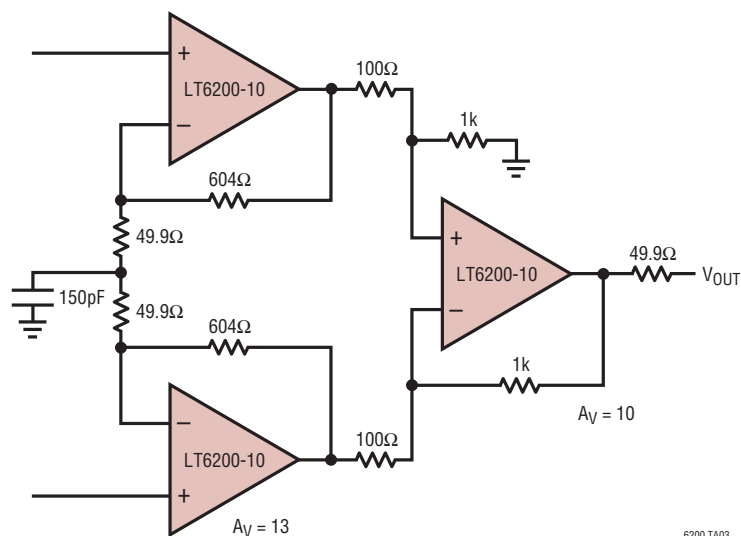
S08 0303

REVISION HISTORY (Revision history begins at Rev D)

REV	DATE	DESCRIPTION	PAGE NUMBER
D	3/10	Change to Input Noise Voltage Density in the Electrical Characteristics section.	7
		Change to X-Axis Range on Graph G61.	17
E	9/11	Updated typical value for t_{ON} in the Electrical Characteristics section.	4-9
		Replaced curves G61 and G78 in the Typical Performance Characteristics section.	17, 19
F	12/11	Revised formatting of Slew Rate and Gain Bandwidth in Electrical Characteristics tables.	4-10

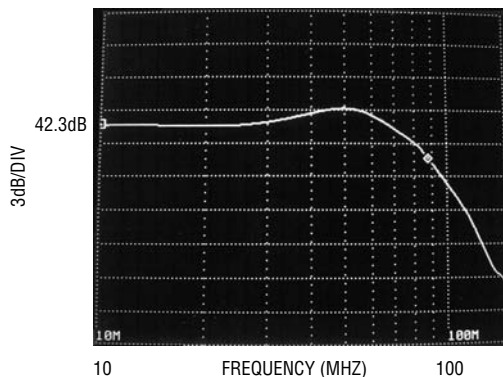
TYPICAL APPLICATION

Rail-to-Rail, High Speed, Low Noise Instrumentation Amplifier



6200 TA03

Instrumentation Amplifier Frequency Response



$A_V = 130$
 $BW_{-3dB} = 85\text{MHz}$
 SLEW RATE = $500\text{V}/\mu\text{s}$
 CMRR = 55dB at 10MHz

6200 TA04

RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1028	Single, Ultralow Noise 50MHz Op Amp	$1.1\text{nV}/\sqrt{\text{Hz}}$
LT1677	Single, Low Noise Rail-to-Rail Amplifier	3V Operation, 2.5mA, $4.5\text{nV}/\sqrt{\text{Hz}}$, $60\mu\text{V}$ Max V_{OS}
LT1722/LT1723/LT1724	Single/Dual/Quad Low Noise Precision Op Amp	$70\text{V}/\mu\text{s}$ Slew Rate, $400\mu\text{V}$ Max V_{OS} , $3.8\text{nV}/\sqrt{\text{Hz}}$, 3.7mA
LT1806/LT1807	Single/Dual, Low Noise 325MHz Rail-to-Rail Amplifier	2.5V Operation, $550\mu\text{V}$ Max V_{OS} , $3.5\text{nV}/\sqrt{\text{Hz}}$
LT6203	Dual, Low Noise, Low Current Rail-to-Rail Amplifier	$1.9\text{nV}/\sqrt{\text{Hz}}$, 3mA Max, 100MHz Gain Bandwidth



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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



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